



Appl. No. 10/062,776

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yoshiyuki Yanagisawa et al.
Appl. No.: 10/062,776
Conf. No.: 3355
Filed: January 30, 2002
Title: DEVICE TRANSFER METHOD AND PANEL
Art Unit: 2812
Examiner: Savitri Mulpuri
Docket No.: 112857-315

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 37 C.F.R. 1.97, and 37 C.F.R. 1.98, Applicants request that a citation and examination of the references cited below, and on the attached PTO-1449 form, copies of which are enclosed, be made during the course of examination of the above/identified application for United States patent.

U.S. PATENT DOCUMENTS

Table with 3 columns: Document No., Date, Inventor. Includes handwritten 'SM' and a vertical line with arrows pointing to the first two rows.

FOREIGN PATENT DOCUMENTS

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Handwritten signatures and date 3/11/04.

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Applicants look forward to early and favorable consideration of this matter.

Respectfully submitted,

BELL, BOYD & LLOYD LLC

BY

A handwritten signature in black ink, appearing to read "Jeffrey H. Canfield".

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Dated: February 12, 2004